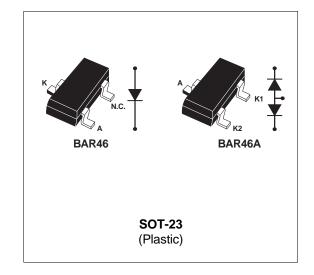


BAR46 BAR46AFILM

SMALL SIGNAL SCHOTTKY DIODES

FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD VOLTAGE DROP
- SURFACE MOUNT DEVICE



DESCRIPTION

High voltage Schottky rectifier suited for SLIC protection during the card insertion operation.

ABSOLUTE RATINGS(limiting values)

Symbol	Parameter	Value	Unit
V _{RRM}	Repetitive peak reverse voltage	100	V
lF	Continuous forward current	150	mA
P _{tot}	Power dissipation (note 1)	230	mW
T _{stg}	Maximum storage temperature range	- 65 to +150	°C
Tj	Maximum operating junction temperature *	150	°C
TL	Maximum temperature for soldering during	260	°C

Note 1: for double diodes, Ptot is the total dissipation of both diodes.

* :
$$\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$$
 thermal runaway condition for a diode on its own heatsink

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth(j-a)	Junction-ambient *	500	°C/W

^{*} Mounted on epoxy board, with recommended pad layout.

September 2002 - Ed: 3A 1/5

BAR46/BAR46AFILM

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test conditions			Тур.	Max.	Unit
V_{BR}	Tj = 25 ℃	$I_R = 100 \mu\text{A}$	100			V
V _F *	Tj = 25 ℃	$I_F = 0.1 \text{ mA}$			0.25	V
	Tj = 25 ℃	$I_F = 10 \text{ mA}$			0.45	
	Tj = 25 ℃	$I_F = 250 \text{ mA}$			1	
I _R **	Tj = 25 °C	$V_R = 1.5 \text{ V}$			0.5	μΑ
	Tj = 60 °C				5	
	Tj = 25 ℃	V _R = 10 V			8.0	
	Tj = 60 °C				7.5	
	Tj = 25 ℃	$V_{R} = 50 \text{ V}$			2	
	Tj = 60 °C				15	
	Tj = 25 ℃	V _R = 75 V			5	
	Tj = 60 °C				20	

DYNAMIC CHARACTERISTICS

Symbol	Test conditions			Min.	Тур.	Max.	Unit
С	Tj = 25 °C	$V_R = 0 V$	F = 1MHz		10		рF
	Tj = 25 °C	V _R = 1 V			6		

Fig. 1: Forward current versus forward voltage at different temperatures (typical values).

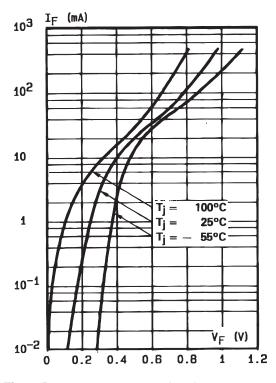


Fig. 3: Reverse current versus junction temperature (typical values).

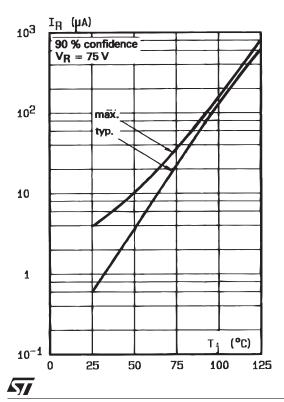


Fig. 2: Forward current versus forward voltage (typical values).

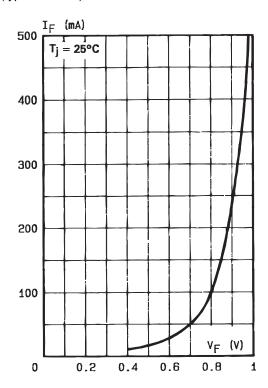


Fig. 4: Reverse current versus continuous reverse voltage (typical values).

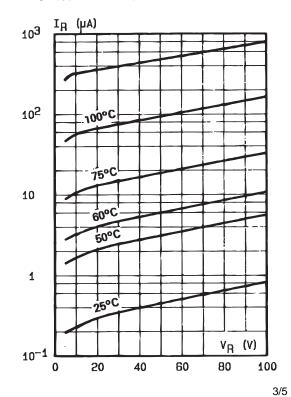
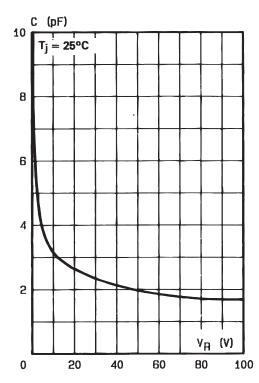


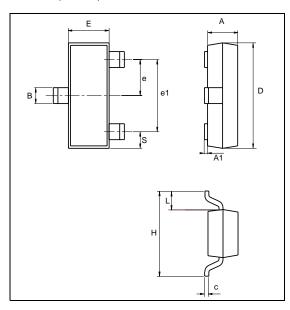
Fig. 5: Capacitance C versus reverse applied voltage V_R (typical values).



4/5

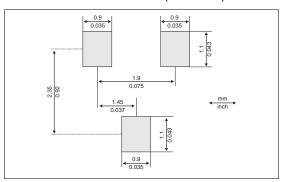
PACKAGE MECHANICAL DATA

SOT-23 (Plastic)



	DIMENSIONS					
REF.	Millin	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	0.89	1.4	0.035	0.055		
A1	0	0.1	0	0.004		
В	0.3	0.51	0.012	0.02		
С	0.085	0.18	0.003	0.007		
D	2.75	3.04	0.108	0.12		
е	0.85	1.05	0.033	0.041		
e1	1.7	2.1	0.067	0.083		
Е	1.2	1.6	0.047	0.063		
Н	2.1	2.75	0.083	0.108		
L	0.6 typ.		0.024 typ.			
S	0.35	0.65	0.014	0.026		

FOOT PRINT DIMENSIONS (Millimeter)



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BAR46	S46	SOT-23	0.01g	3000	Tape & reel
BAR46AFILM	A46	SOT-23	0.01g	3000	Tape & reel

■ Epoxy meets UL94,V0

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied.

change without notice. This publication supersedes and replaces all information previously supplied.

STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics

© 2002 STMicroelectronics - Printed in Italy - All rights reserved.

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore

Spain - Sweden - Switzerland - United Kingdom - United States.

http://www.st.com

5//

5/5